imall

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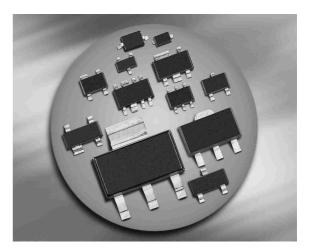


Silicon Schottky Diode

- For mixer applications in VHF/UHF range
- For high-speed switching application
- Pb-free (RoHS compliant) package



BAT17



BAT17-06W





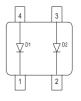




BAT17-05

BAT17-05W





ESD (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Package	Configuration	L _S (nH)	Marking
BAT17	SOT23	single	1.8	53s
BAT17-04	SOT23	series	1.8	54s
BAT17-04W	SOT323	series	1.4	54s
BAT17-05	SOT23	common cathode	1.8	55s
BAT17-05W	SOT323	common cathode	1.4	55s
BAT17-06W	SOT323	common anode	1.4	56s
BAT17-07	SOT143	parallel pair	2	57s



Maximum Rating	s at $T_A = 25^{\circ}C$,	unless otherwise specified
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Parameter	Symbol	Value	Unit V	
Diode reverse voltage	V _R	4		
Forward current	/ _F	130	mA	
Total power dissipation	P _{tot}		mW	
BAT17, <i>T</i> _S ≤ 77°C		150		
BAT17-04, <i>T</i> _S ≤ 61°C		150		
BAT17-05, <i>T</i> _S ≤ 46°C		150		
BAT17-04W, -05W, -6W, <i>T</i> _S ≤ 92 °C		150		
BAT17-07, <i>T</i> _S ≤ 60 °C		150		
Junction temperature	T _i 150		°C	
Operating temperature range	T _{op}	-55 125		
Storage temperature	T _{stg}	-55 150		

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R _{thJS}		K/W
BAT17		≤ 4 90	
BAT17-04, BAT17-07		≤ 5 90	
BAT17-05		≤ 690	
BAT17-04W, BAT17-05W, BAT17-06W		≤ 3 90	

¹For calculation of $R_{\rm thJA}$ please refer to Application Note Thermal Resistance



Parameter	Symbol		Values		
		min.	typ.	max.	
DC Characteristics					
Breakdown voltage	V _(BR)	4	-	-	V
<i>I</i> _(BR) = 10 μA					
Reverse current	I _R				μA
V_{R} = 3 V		-	-	0.25	
V_{R} = 4 V		-	-	10	
$V_{\rm R}$ = 3 V, $T_{\rm A}$ = 60 °C		-	-	1.25	
Forward voltage	V _F				mV
<i>I</i> _F = 0.1 mA		200	275	350	
<i>I</i> _F = 1 mA		250	340	450	
<i>I</i> _F = 10 mA		350	425	600	
Forward voltage matching ¹⁾	ΔV_{F}	-	-	20	
/ _F = 1 mA					
AC Characteristics					
Diode capacitance	CT	0.4	0.55	0.75	pF
V _R = 0 , <i>f</i> = 1 MHz					
Differential forward resistance	R _F	-	8	15	Ω
<i>I</i> _F = 5 mA, <i>f</i> = 10 kHz					

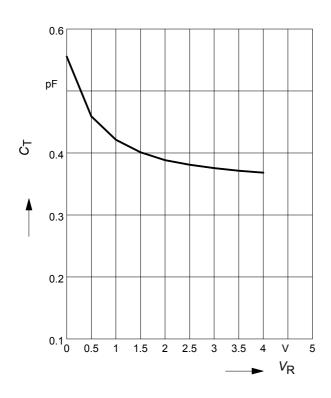
Electrical Characteristics at $T_A = 25^{\circ}C$, unless otherwise specified

 $^{1}\Delta V_{F}$ is the difference between lowest and highest V_{F} in multiple diode component.



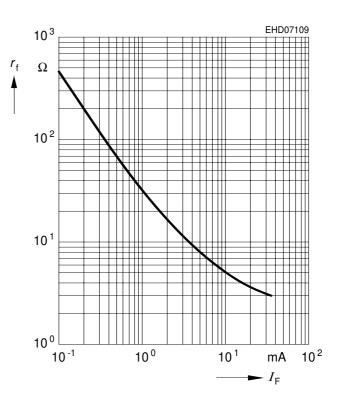
Diode capacitance $C_{T} = f(V_{R})$

f = 1 MHz



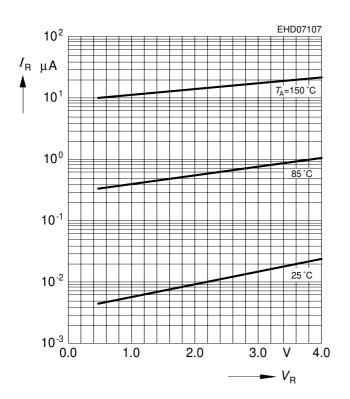
Forward resistance $r_{\rm f} = f (I_{\rm F})$

f = 10kHz

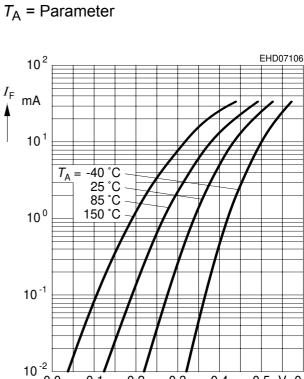


Reverse current $I_{R} = f(V_{R})$

 T_A = Parameter



Forward current $I_{\rm F} = f(V_{\rm F})$



► V_F

0.5 V 0.6

0.0

0.1

0.2

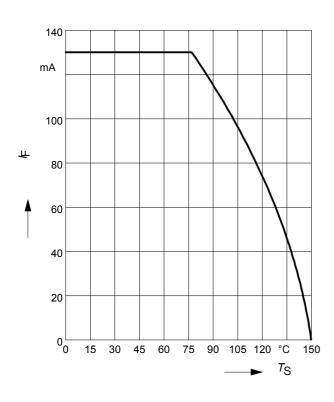
0.3

0.4

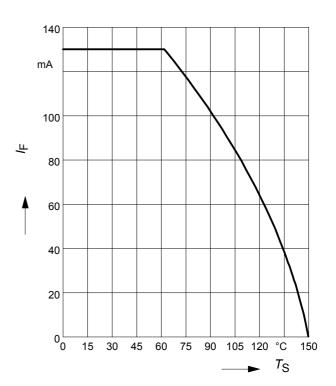


BAT17...

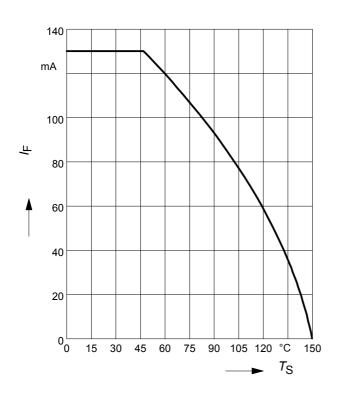
Forward current $I_{\mathsf{F}} = f(T_{\mathsf{S}})$ BAT17



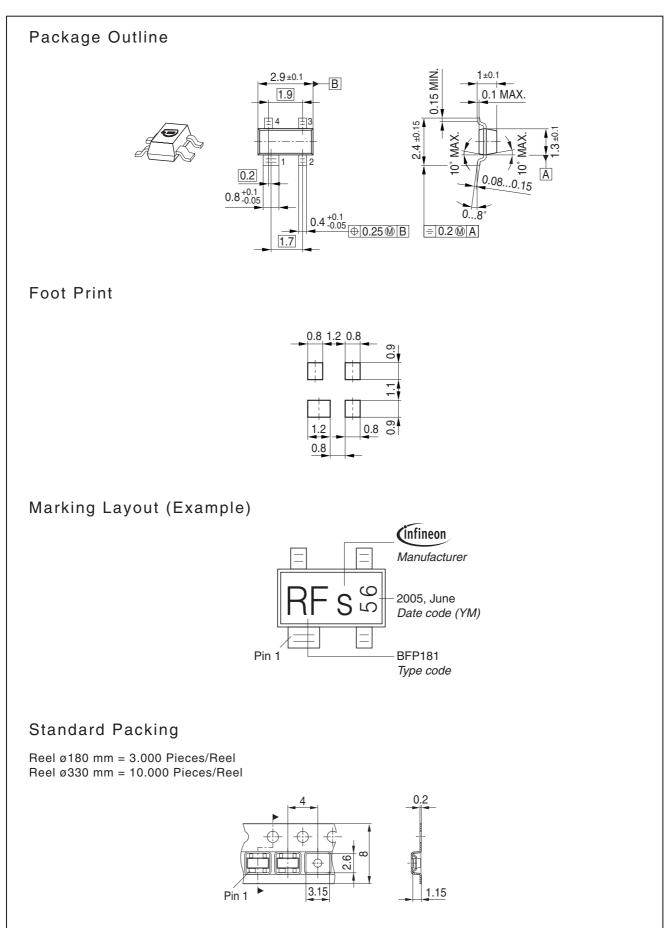
Forward current $I_{\rm F}$ = $f(T_{\rm S})$ BAT17-04, BAT17-07



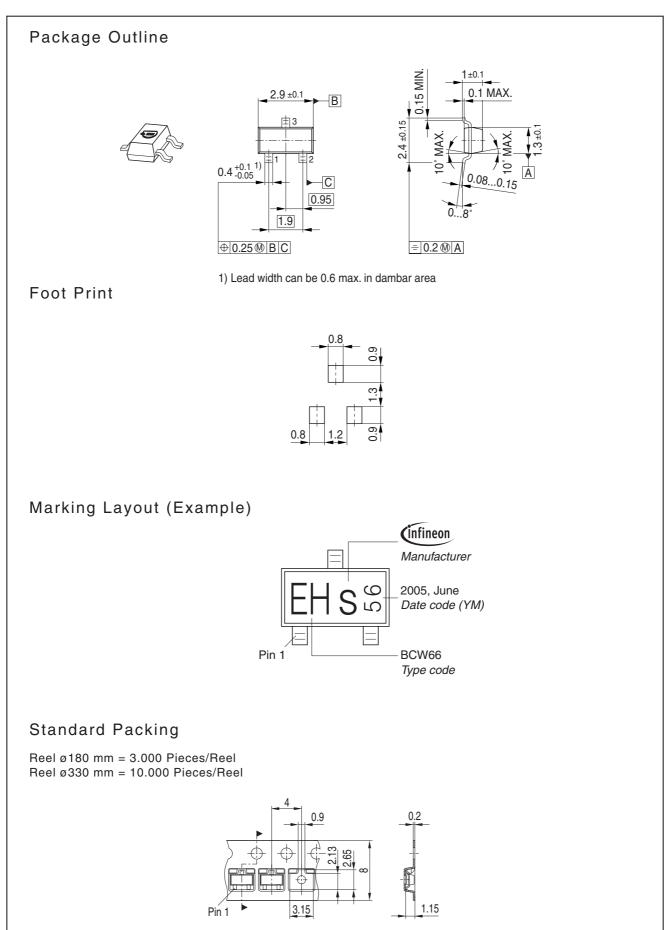
Forward current $I_{F} = f(T_{S})$ BAT17-05



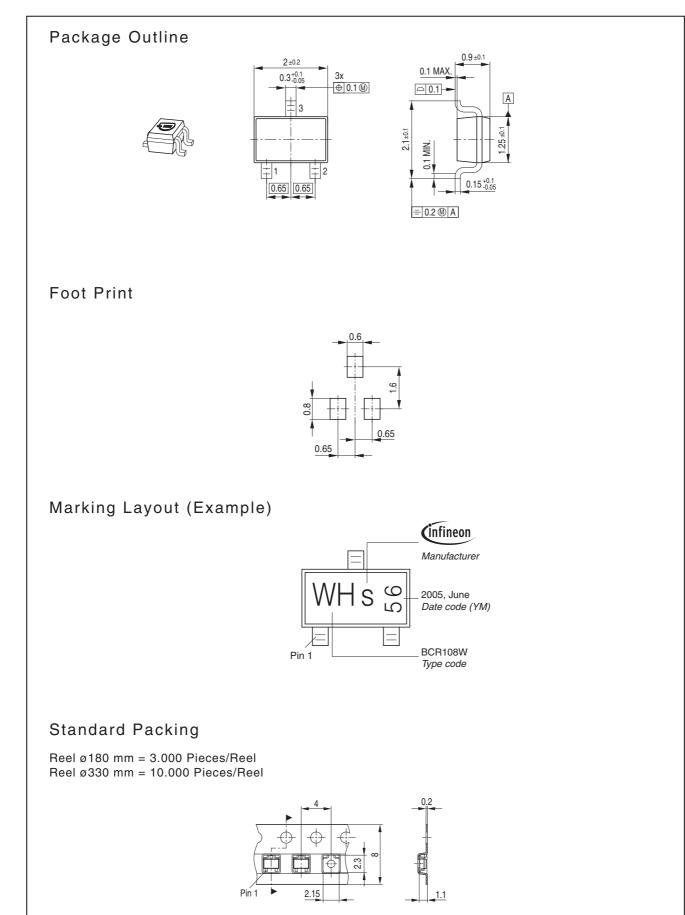
















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